

BC847PNQ

COMPLEMENTARY PAIR SMALL SIGNAL TRANSISTOR IN SOT363

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

Features

- **Epitaxial Die Construction**
- Two Internally Isolated NPN/PNP Transistors in One Package
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

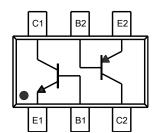
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)





Top View



Device Schematic Top View

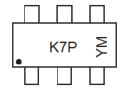
Ordering Information (Notes 4 & 5)

| Part Number | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|---------------|------------|---------|--------------------|-----------------|-------------------|
| BC847PNQ-7-F | Automotive | K7P | 7 | 8 | 3,000 |
| BC847PNQ-7R-F | Automotive | K7P | 7 | 8 | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K7P = Product Type Marking Code YM = Date Code Marking Y = Year (ex: D = 2016)M = Month (ex: 9 = September)

Date Code Key

| Year | 2015 | 201 | 6 | 2017 | 20 | 18 | 2019 | 2 | 2020 | 2021 | | 2022 |
|-------|------|-----|-----|------|-----|-----|------|-----|------|------|-----|------|
| Code | С | D | | Е | | F | G | | Н | l | | J |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |

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Absolute Maximum Ratings: NPN, BC847B Type (Q₁) (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 50 | V |
| Collector-Emitter Voltage | V _{CEO} | 45 | V |
| Emitter-Base Voltage | V_{EBO} | 6 | V |
| Collector Current | Ic | 100 | mA |
| Peak Collector Current | I _{CM} | 200 | mA |
| Peak Emitter Current | I _{EM} | 200 | mA |

Absolute Maximum Ratings: PNP, BC857B Type (Q₂) (@T_A = +25°C, unless otherwise specified.)

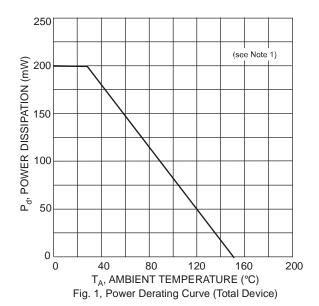
| Characteristic | Symbol | Value | Unit |
|---------------------------|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | -50 | V |
| Collector-Emitter Voltage | V _{CEO} | -45 | V |
| Emitter-Base Voltage | V _{EBO} | -6 | V |
| Collector Current | Ic | -100 | mA |
| Peak Collector Current | I _{CM} | -200 | mA |
| Peak Emitter Current | I _{EM} | -200 | mA |

Thermal Characteristics – Total Device (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 6) Total Device | P_{D} | 200 | mW |
| Thermal Resistance, Junction to Ambient (Note 6) | $R_{	hetaJA}$ | 625 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -65 to +150 | °C |

Note:

Thermal Characteristics – Total Device



^{6.} For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR-4 PCB; the device is measured under still air conditions whilst operating in a steady-state.



Electrical Characteristics: NPN, BC847B Type (Q₁) (@T_A = +25°C, unless otherwise specified.)

| Characteristic (Note 7) | Symbol | Min | Тур | Max | Unit | Test Condition |
|--------------------------------------|----------------------|----------|------------|------------|----------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | 50 | 1 | _ | V | $I_{C} = 100 \mu A$ |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | 45 | _ | _ | V | I _C = 10mA |
| Emitter-Base Breakdown Voltage | BV_{EBO} | 6 | 1 | _ | V | $I_{E} = 100 \mu A$ |
| DC Current Gain | h _{FE} | 200 | 290 | 450 | _ | $V_{CE} = 5.0V, I_{C} = 2.0mA$ |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | _ | 90 200 | 250 600 | mV | $I_C = 10mA$, $I_B = 0.5mA$ $I_C = 100mA$, $I_B = 5.0mA$ |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | 1 | 700 900 | | mV | $I_C = 10$ mA, $I_B = 0.5$ mA $I_C = 100$ mA, $I_B = 5.0$ mA |
| Base-Emitter Voltage | V _{BE(ON)} | 580 — | 660 — | 700 720 | mV | $V_{CE} = 5.0V, I_{C} = 2.0mA$ $V_{CE} = 5.0V, I_{C} = 10mA$ |
| Collector-Cutoff Current | I _{CBO} | | | 15 5.0 | nΑ μΑ | V _{CB} = 30V V _{CB} = 30V, T _A = +150°C |
| Gain Bandwidth Product | f⊤ | 100 | 300 | | MHz | $V_{CE} = 5.0V, I_{C} = 10mA,$ f = 100MHz |
| Collector-Base Capacitance | C _{CBO} | | 3.5 | 6.0 | pF | V _{CB} = 10V, f = 1.0MHz |
| Noise Figure | NF | | 2.0 | 10 | dB | $V_{CE} = 5V, I_C = 200\mu A, \ R_g = 2.0k\Omega, f = 1.0kHz, \ \Delta f = 200Hz$ |

Note:

7. Short duration pulse test used to minimize self-heating effect.

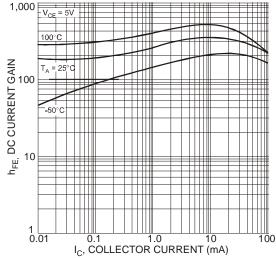


Figure 2. Typical DC Current Gain vs. Collector Current (BC847B Type)

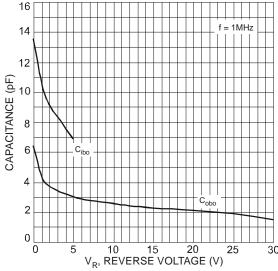


Figure 4. Typical Capacitance Characteristics (BC847B Type)

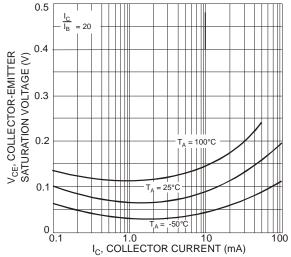


Figure 3. Typical Collector-Emitter Saturation Voltage vs. Collector Current (BC847B Type)

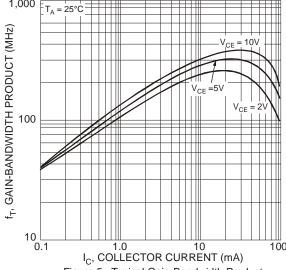


Figure 5. Typical Gain-Bandwidth Product vs. Collector Current (BC847B Type)



Electrical Characteristics: PNP, BC857B Type (Q₂) (@T_A = +25°C unless otherwise specified.)

| Characteristic (Note 8) | Symbol | Min | Тур | Max | Unit | Test Condition |
|--------------------------------------|----------------------|-----------|--------------|--------------|----------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | -50 | | _ | V | $I_C = -100 \mu A$ |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | -45 | _ | _ | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -6 | _ | _ | V | $I_E = -100 \mu A$ |
| DC Current Gain | h _{FE} | 220 | 290 | 475 | _ | $V_{CE} = -5.0V, I_{C} = -2.0mA$ |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | ı | -75 -250 | -300 -650 | mV | $I_C = -10$ mA, $I_B = -0.5$ mA $I_C = -100$ mA, $I_B = -5.0$ mA |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | l | -700 -850 | — -950 | mV | $I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$ $I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$ |
| Base-Emitter Voltage | V _{BE(ON)} | -600 — | -650 — | -750 -820 | mV | $V_{CE} = -5.0V, I_{C} = -2.0mA$ $V_{CE} = -5.0V, I_{C} = -10mA$ |
| Collector-Cutoff Current | I _{CBO} | _ | | -15 -4.0 | nΑ μΑ | V _{CB} = -30V V _{CB} = -30V, T _A = +150°C |
| Gain Bandwidth Product | f _T | 100 | 200 | | MHz | $V_{CE} = -5.0V, I_{C} = -10mA,$ f = 100MHz |
| Collector-Base Capacitance | C _{CBO} | | 3 | 4.5 | pF | $V_{CB} = -10V, f = 1.0MHz$ |
| Noise Figure | NF | | | 10 | dB | $V_{CE} = -5V, I_C = -200\mu A, \ R_g = 2.0k\Omega, f = 1.0kHz, \ \Delta f = 200Hz$ |

Note: 8. Short duration pulse test used to minimize self-heating effect.

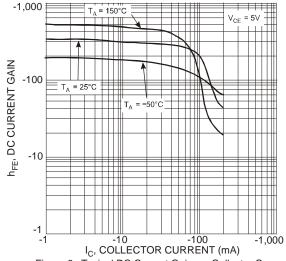


Figure 6. Typical DC Current Gain vs. Collector Current (BC857B Type)

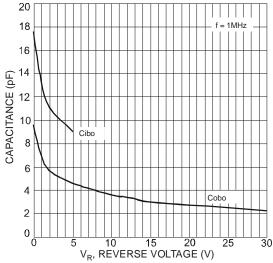


Figure 8. Typical Capacitance Characteristics (BC857B Type)

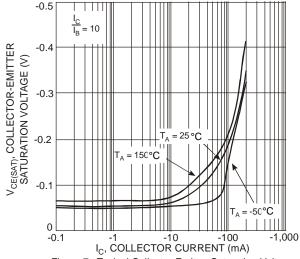


Figure 7. Typical Collector-Emitter Saturation Voltage vs. Collector Current (BC857B Type)

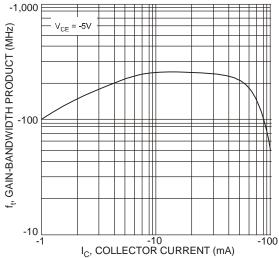


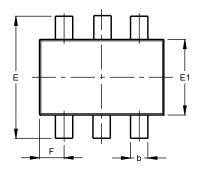
Figure 9. Typical Gain-Bandwidth Product vs. Collector Current (BC857B Type)

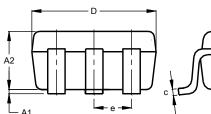


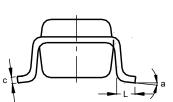
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363





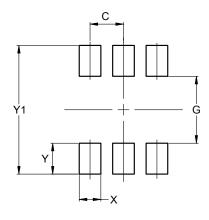


| | SOT363 | | | | | | | |
|----------------------|--------|-----------|-------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| A1 | 0.00 | 0.10 | 0.05 | | | | | |
| A2 | 0.90 | 1.00 | 1.00 | | | | | |
| b | 0.10 | 0.30 | 0.25 | | | | | |
| С | 0.10 | 0.22 | 0.11 | | | | | |
| D | 1.80 | 2.20 | 2.15 | | | | | |
| Е | 2.00 | 2.20 | 2.10 | | | | | |
| E1 | 1.15 | 1.35 | 1.30 | | | | | |
| е | (| 0.650 BSC | | | | | | |
| F | 0.40 | 0.45 | 0.425 | | | | | |
| L | 0.25 | 0.40 | 0.30 | | | | | |
| а | 0° | 8° | | | | | | |
| All Dimensions in mm | | | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.650 |
| G | 1.300 |
| Х | 0.420 |
| Y | 0.600 |
| Y1 | 2.500 |



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